

Precision CMOS Analog Switches

DESCRIPTION

The DG417/418/419 monolithic CMOS analog switches were designed to provide high performance switching of analog signals. Combining low power, low leakages, high speed, low on-resistance and small physical size, the DG417 series is ideally suited for portable and battery powered industrial and military applications requiring high performance and efficient use of board space.

To achieve high-voltage ratings and superior switching performance, the DG417 series is built on Vishay Siliconix's high voltage silicon gate (HVSG) process. Break-before-make is guaranteed for the DG419, which is an SPDT configuration. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG417 and DG418 respond to opposite control logic levels as shown in the Truth Table.

FEATURES

- ± 15 V Analog Signal Range
- On-Resistance - $r_{DS(on)}$: 20 Ω
- Fast Switching Action - t_{ON} : 100 ns
- Ultra Low Power Requirements - P_D : 35 nW
- TTL and CMOS Compatible
- MiniDIP and SOIC Packaging
- 44 V Supply Max Rating



RoHS*
COMPLIANT

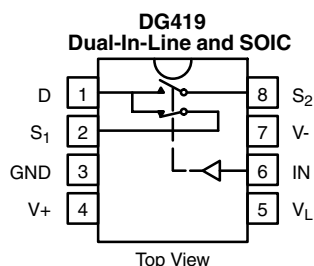
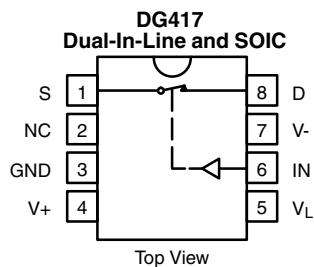
BENEFITS

- Wide Dynamic Range
- Low Signal Errors and Distortion
- Break-Before-Make Switching Action
- Simple Interfacing
- Reduced Board Space
- Improved Reliability

APPLICATIONS

- Precision Test Equipment
- Precision Instrumentation
- Battery Powered Systems
- Sample-and-Hold Circuits
- Military Radios
- Guidance and Control Systems
- Hard Disk Drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

| Logic | DG417 | DG418 |
|-------|-------|-------|
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V

TRUTH TABLE - DG419

| Logic | SW ₁ | SW ₂ |
|-------|-----------------|-----------------|
| 0 | ON | OFF |
| 1 | OFF | ON |

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply



| ORDERING INFORMATION | | |
|----------------------|-----------------------|--|
| Temp Range | Package | Part Number |
| DG417/DG418 | | |
| - 40 to 85 °C | 8-Pin Plastic MiniDIP | DG417DJ DG417DJ-E3 |
| | | DG418DJ DG418DJ-E3 |
| | 8-Pin Narrow SOIC | DG417DY DG417DY-E3 DG417DY-T1 DG417DY-T1-E3 |
| | | DG418DY DG418DY-E3 DG418DY-T1 DG418DY-T1-E3 |
| DG419 | | |
| - 40 to 85 °C | 8-Pin Plastic MiniDIP | DG419DJ DG419DJ-E3 |
| | 8-Pin Narrow SOIC | DG419DY DG419DY-E3 DG419DY-T1 DG419DY-T1-E3 |

| ABSOLUTE MAXIMUM RATINGS | | | |
|---|--|-------------|----|
| Parameter | Limit | Unit | |
| Voltages Referenced V+ to V- | 44 | V | |
| GND | 25 | | |
| V _L | (GND - 0.3) to (V+) + 0.3 | | |
| Digital Inputs ^a , V _S , V _D | (V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first | | |
| Current, (Any Terminal) Continuous | 30 | mA | |
| Current, S or D (Pulsed at 1 ms, 10 % duty cycle) | 100 | | |
| Storage Temperature | (AK Suffix) | - 65 to 150 | °C |
| | (DJ, DY Suffix) | - 65 to 125 | |
| Power Dissipation (Package) ^b | 8-Pin Plastic MiniDIP ^c | 400 | mW |
| | 8-Pin Narrow SOIC ^d | 400 | |
| | 8-Pin CerDIP ^e | 600 | |

Notes:

- a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6 mW/°C above 75 °C.
- d. Derate 6.5 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.

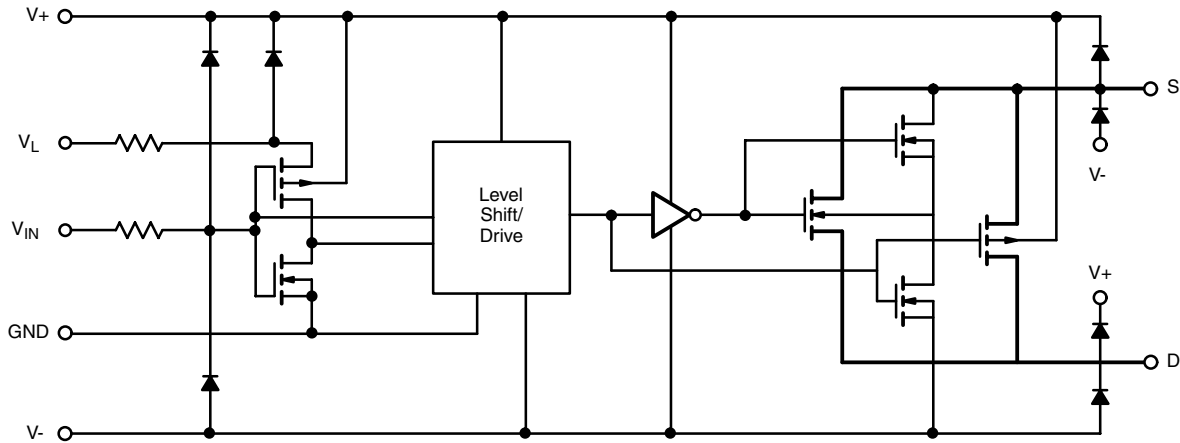
SCHEMATIC DIAGRAM (TYPICAL CHANNEL)


Figure 1.

| SPECIFICATIONS^a | | | | | | | | | | |
|--------------------------------------|--------------|--|-------------------------|------------------|----------------------------|------------------|---------------------------|------------------|---------------|------------|
| Parameter | Symbol | Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}$, $V_- = -15\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f | Temp ^b | Typ ^c | A Suffix - 55 to 125 °C | | D Suffix - 40 to 85 °C | | Unit | |
| | | | | | Min ^d | Max ^d | Min ^d | Max ^d | | |
| Analog Switch | | | | | | | | | | |
| Analog Signal Range ^e | V_{ANALOG} | | Full | | - 15 | 15 | - 15 | 15 | V | |
| Drain-Source On-Resistance | $r_{DS(on)}$ | $I_S = -10\text{ mA}$, $V_D = \pm 12.5\text{ V}$ $V_+ = 13.5\text{ V}$, $V_- = -13.5\text{ V}$ | Room Full | 20 | | 35 45 | | 35 45 | Ω | |
| Switch Off Leakage Current | $I_{S(off)}$ | $V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_D = \pm 15.5\text{ V}$ $V_S = \pm 15.5\text{ V}$ | Room Full | - 0.1 | - 0.25 - 20 | 0.25 20 | - 0.25 - 5 | 0.25 5 | nA | |
| | $I_{D(off)}$ | | DG417 DG418 | Room Full | - 0.1 | - 0.25 - 20 | 0.25 20 | - 0.25 - 5 | | 0.25 5 |
| | | | DG419 | Room Full | - 0.1 | - 0.75 - 60 | 0.75 60 | - 0.75 - 12 | | 0.75 12 |
| Channel Off Leakage Current | $I_{D(on)}$ | $V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_S = V_D = \pm 15.5\text{ V}$ | DG417 DG418 DG419 | Room Full | - 0.4 - 40 - 60 | 0.4 40 60 | - 0.4 - 10 - 12 | 0.4 10 12 | | |
| Digital Control | | | | | | | | | | |
| Input Current V_{IN} Low | I_{IL} | | Full | 0.005 | - 0.5 | 0.5 | - 0.5 | 0.5 | μA | |
| Input Current V_{IN} High | I_{IH} | | Full | 0.005 | - 0.5 | 0.5 | - 0.5 | 0.5 | | |
| Dynamic Characteristics | | | | | | | | | | |
| Turn-On Time | t_{ON} | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = \pm 10\text{ V}$ See Switching Time Test Circuit | DG417 DG418 | Room Full | 100 | | 175 250 | | 175 250 | ns |
| Turn-Off Time | t_{OFF} | | DG417 DG418 | Room Full | 60 | | 145 210 | | 145 210 | |
| Transition Time | t_{TRANS} | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = \pm 10\text{ V}$, $V_{S2} = \pm 10\text{ V}$ | DG419 | Room Full | | | 175 250 | | 175 250 | |
| Break-Before-Make Time Delay (DG403) | t_D | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = V_{S2} = \pm 10\text{ V}$ | DG419 | Room | 13 | 5 | | 5 | | |
| Charge Injection | Q | $C_L = 10\text{ nF}$, $V_{gen} = 0\text{ V}$, $R_{gen} = 0\ \Omega$ | | Room | 60 | | | | | pC |
| Source Off Capacitance | $C_{S(off)}$ | $f = 1\text{ MHz}$, $V_S = 0\text{ V}$ | | Room | 8 | | | | | pF |
| Drain Off Capacitance | $C_{D(off)}$ | | DG417 DG418 | Room | 8 | | | | | |
| Channel On Capacitance | $C_{D(on)}$ | | DG417 DG418 DG419 | Room | 30 35 | | | | | |



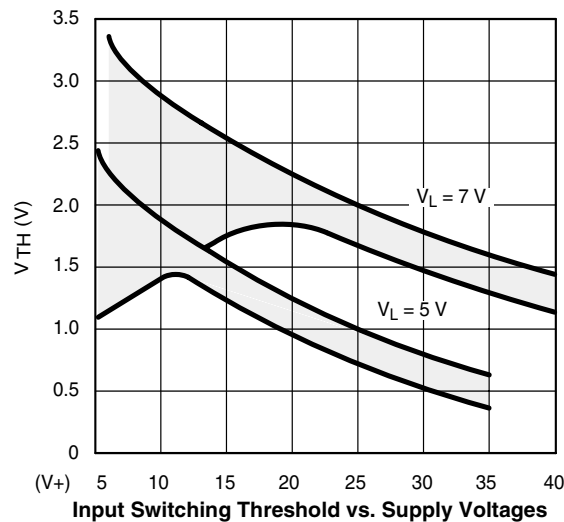
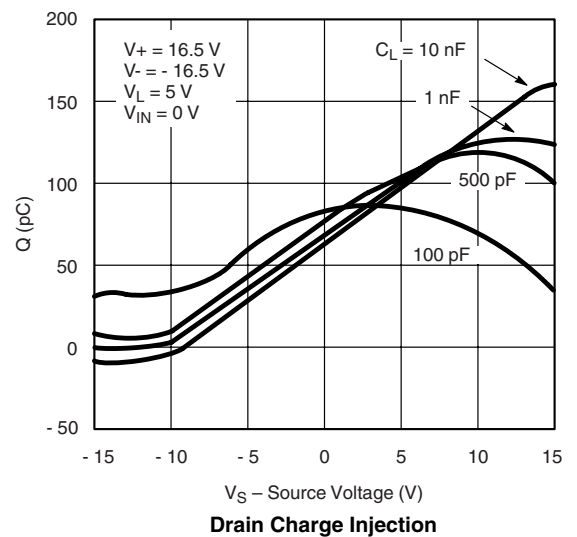
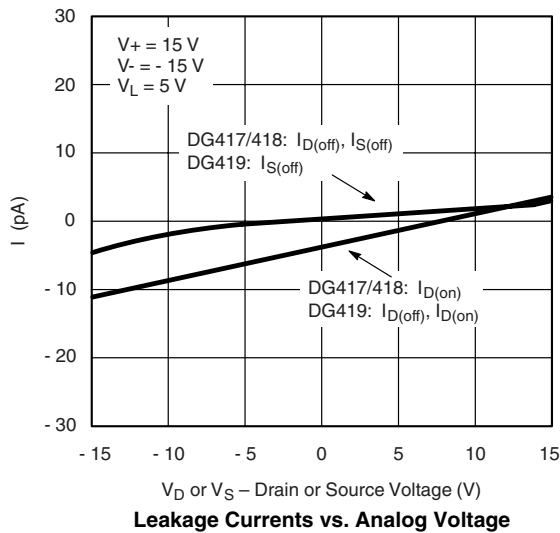
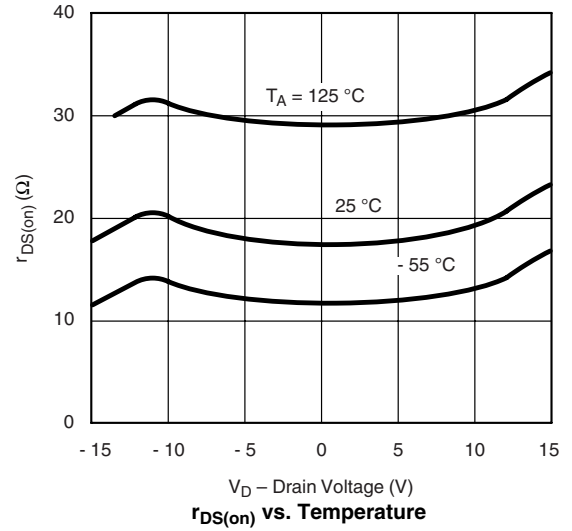
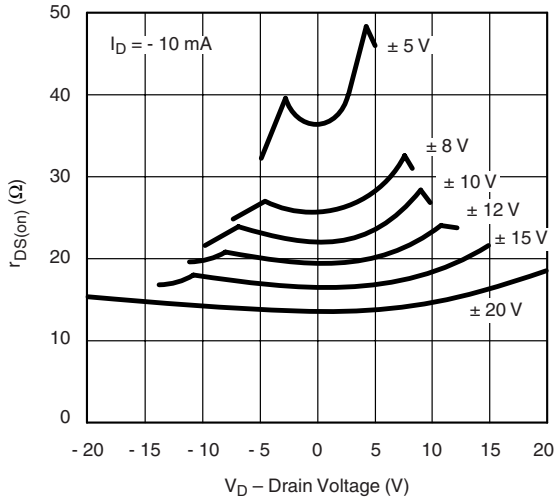
| SPECIFICATIONS ^a | | | | | | | | | |
|-----------------------------|------------------|--|-------------------|------------------|----------------------------|------------------|---------------------------|------------------|------|
| Parameter | Symbol | Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}$, $V_- = -15\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f | Temp ^b | Typ ^c | A Suffix - 55 to 125 °C | | D Suffix - 40 to 85 °C | | Unit |
| | | | | | Min ^d | Max ^d | Min ^d | Max ^d | |
| Power Supplies | | | | | | | | | |
| Positive Supply Current | I ₊ | $V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_{IN} = 0$ or 5 V | Room Full | 0.001 | | 1 5 | | 1 5 | μA |
| Negative Supply Current | I ₋ | | Room Full | -0.001 | -1 -5 | | -1 -5 | | |
| Logic Supply Current | I _L | | Room Full | 0.001 | | 1 5 | | 1 5 | |
| Ground Current | I _{GND} | | Room Full | -0.0001 | -1 -5 | | -1 -5 | | |

| SPECIFICATIONS FOR UNIPOLAR SUPPLIES ^a | | | | | | | | | |
|---|---------------------|--|-------------------|------------------|----------------------------|------------------|---------------------------|------------------|------|
| Parameter | Symbol | Test Conditions Unless Otherwise Specified $V_+ = 12\text{ V}$, $V_- = 0\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f | Temp ^b | Typ ^c | A Suffix - 55 to 125 °C | | D Suffix - 40 to 85 °C | | Unit |
| | | | | | Min ^d | Max ^d | Min ^d | Max ^d | |
| Analog Switch | | | | | | | | | |
| Analog Signal Range ^e | V _{ANALOG} | | Full | | 0 | 12 | 0 | 12 | V |
| Drain-Source On-Resistance | r _{DS(on)} | I _S = -10 mA, V _D = 3.8 V V ₊ = 10.8 V | Room | 40 | | | | | Ω |
| Dynamic Characteristics | | | | | | | | | |
| Turn-On Time | t _{ON} | R _L = 300 Ω, C _L = 35 pF, V _S = 8 V See Switching Time Test Circuit | Room | 110 | | | | | ns |
| Turn-Off Time | t _{OFF} | | Room | 40 | | | | | |
| Break-Before-Make Time Delay | t _D | DG419 Only R _L = 300 Ω, C _L = 35 pF | Room | 60 | | | | | |
| Charge Injection | Q | C _L = 10 nF, V _{gen} = 0 V, R _{gen} = 0 Ω | Room | 5 | | | | | pC |
| Power Supplies | | | | | | | | | |
| Positive Supply Current | I ₊ | $V_+ = 13.2\text{ V}$, $V_L = 5.25\text{ V}$ $V_{IN} = 0$ or 5 V | Room | 0.001 | | | | | μA |
| Negative Supply Current | I ₋ | | Room | -0.001 | | | | | |
| Logic Supply Current | I _L | | Room | 0.001 | | | | | |
| Ground Current | I _{GND} | | Room | -0.001 | | | | | |

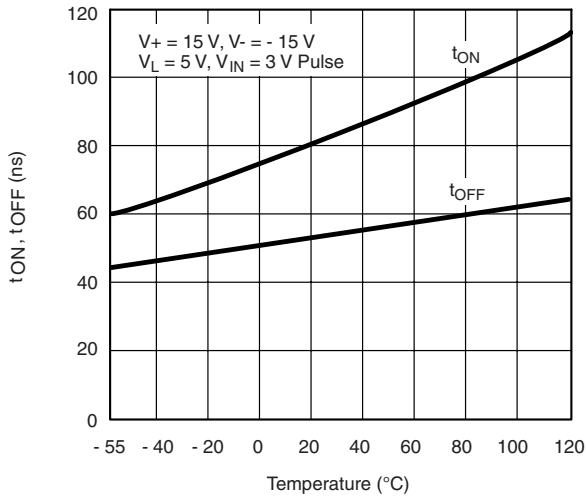
Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

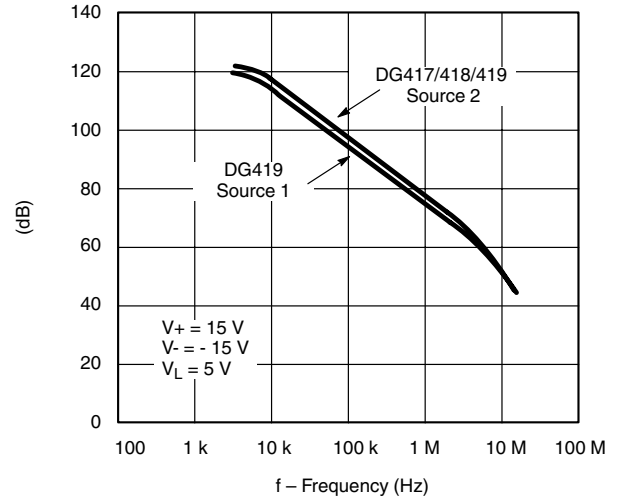
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted


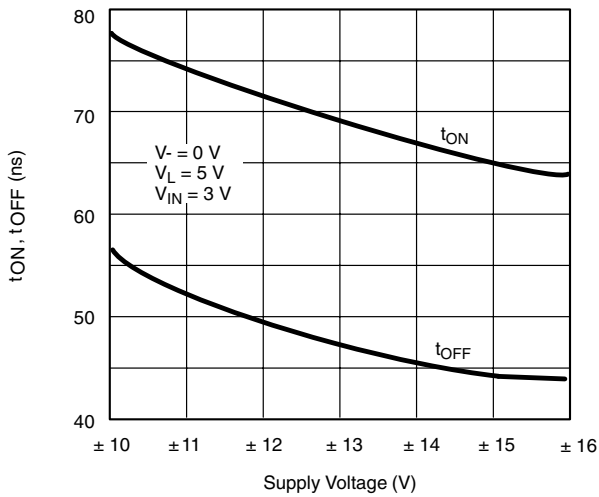
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



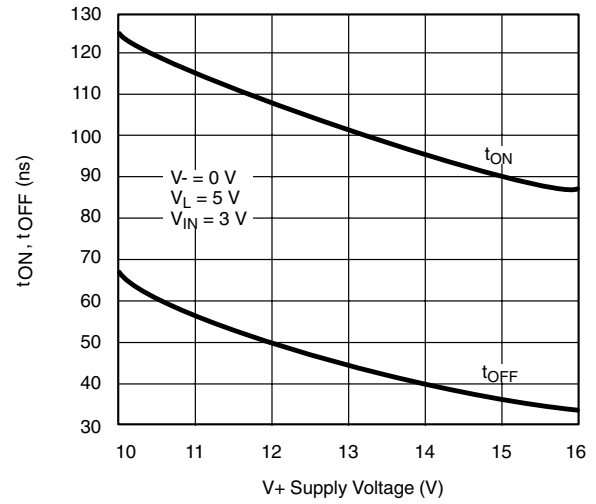
Switching Time vs. Temperature



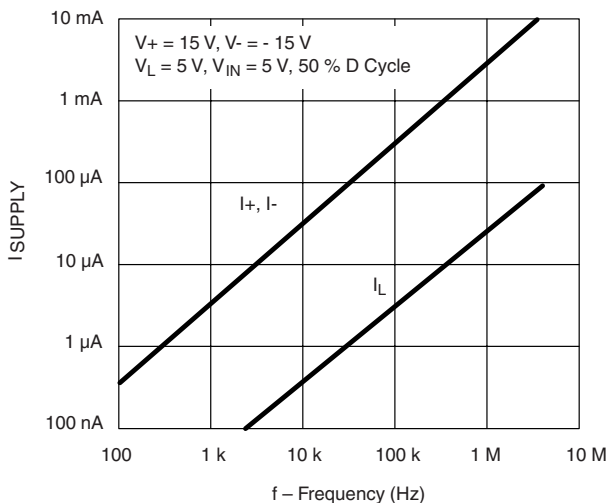
Crosstalk and Off Isolation vs. Frequency



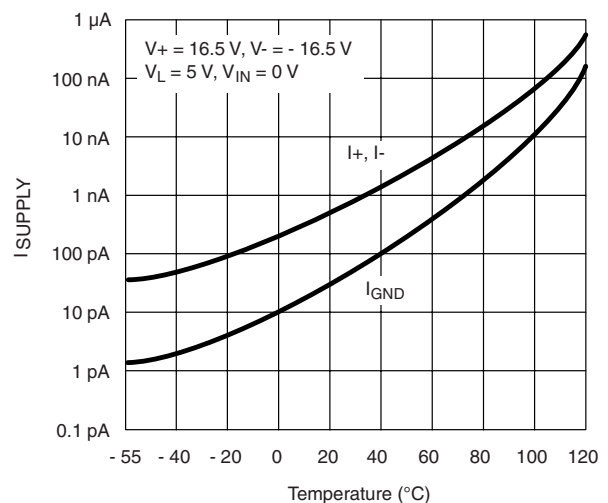
Switching Time vs. Supply Voltages



Switching Time vs. V_+



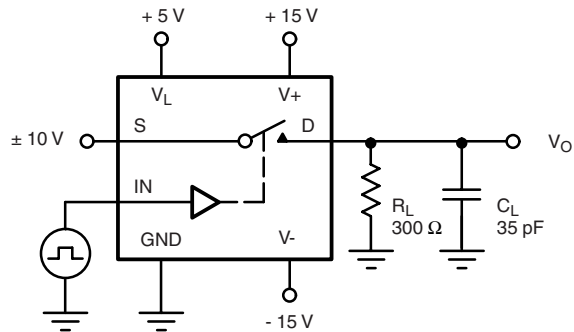
Power Supply Currents vs. Switching Frequency



Supply Current vs. Temperature

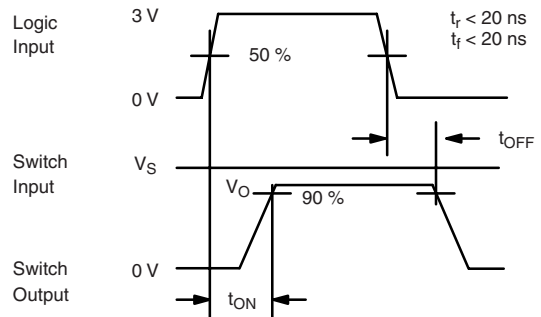
TEST CIRCUITS

V_O is the steady state output with the switch on.

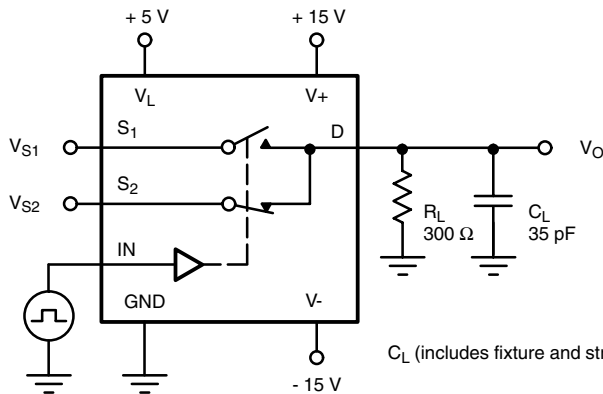


C_L (includes fixture and stray capacitance)

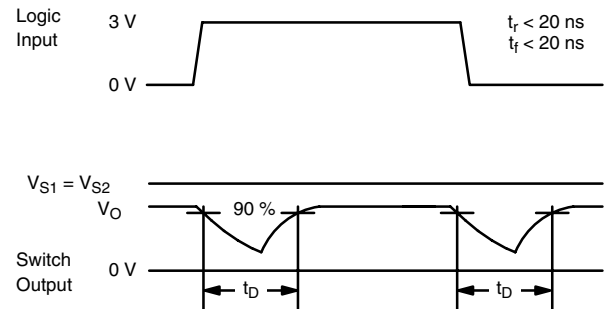
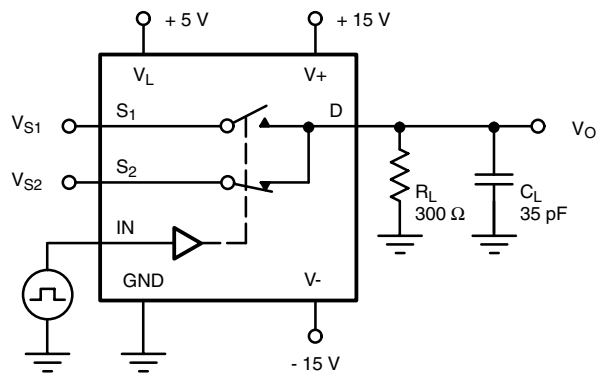
$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

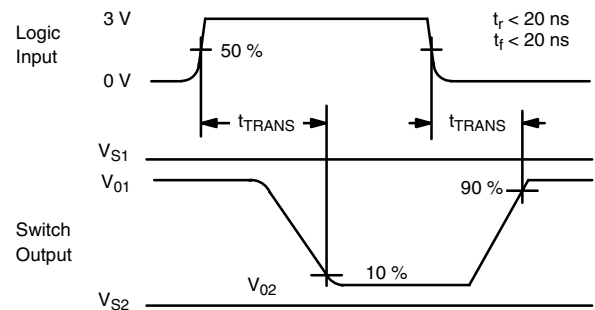
Figure 2. Switching Time (DG417/418)


C_L (includes fixture and stray capacitance)


Figure 3. Break-Before-Make (DG419)


C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$


Figure 4. Transition Time (DG419)

TEST CIRCUITS

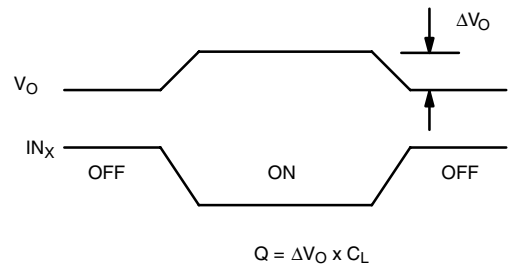
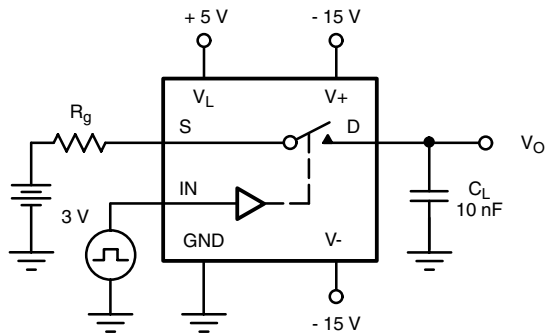
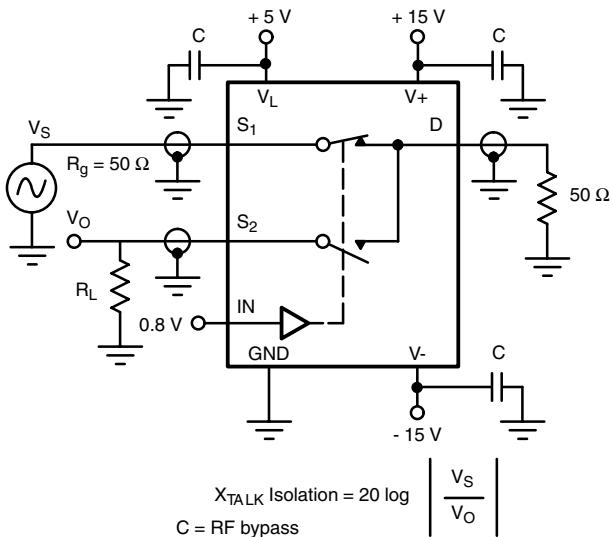


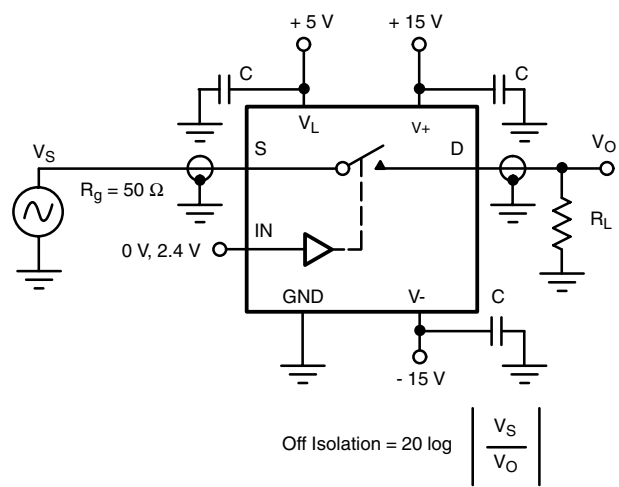
Figure 5. Charge Injection



$$X_{\text{TALK Isolation}} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

Figure 6. Crosstalk (DG419)



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

Figure 7. Off Isolation

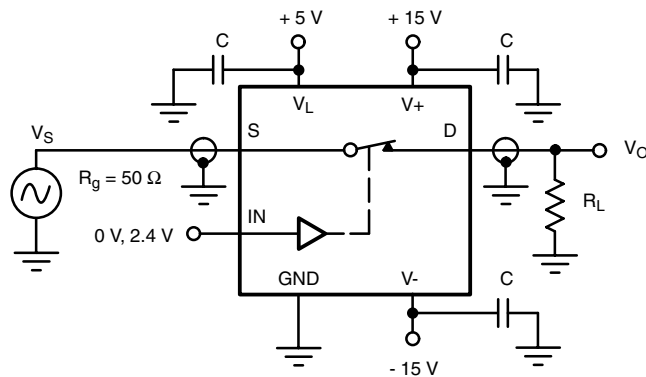
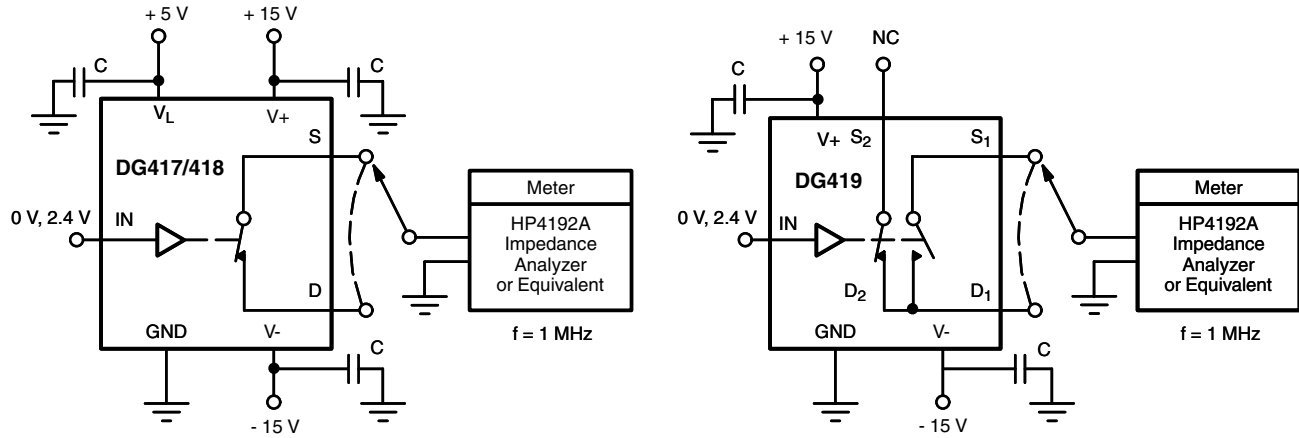


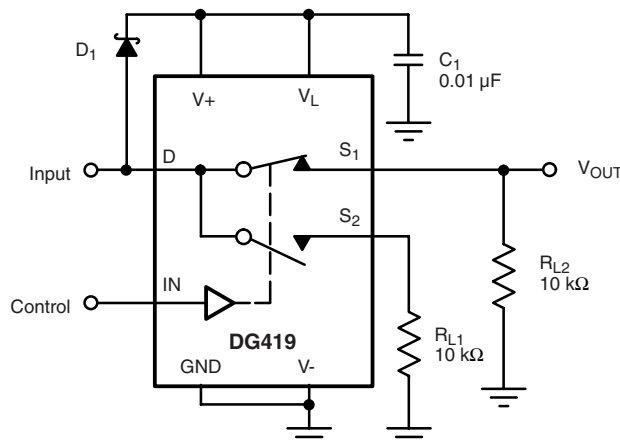
Figure 8. Insertion Loss

TEST CIRCUITS

Figure 9. Source/Drain Capacitances
APPLICATIONS
Switched Signal Powers Analog Switch

The analog switch in Figure 10 derives power from its input signal, provided the input signal amplitude exceeds 4 V and its frequency exceeds 1 kHz.

This circuit is useful when signals have to be routed to either of two remote loads. Only three conductors are required: one for the signal to be switched, one for the control signal and a common return.

A positive input pulse turns on the clamping diode D_1 and charges C_1 . The charge stored on C_1 is used to power the chip; operation is satisfactory because the switch requires less than 1 μA of stand-by supply current. Loading of the signal source is imperceptible. The DG419's on-resistance is a low 100 Ω for a 5 V input signal.


Figure 10. Switched Signal Powers Remote SPDT Analog Switch

APPLICATIONS

Micropower UPS Transfer Switch

When V_{CC} drops to 3.3 V, the DG417 changes states, closing SW_1 and connecting the backup cell, as shown in Figure 10. D_1 prevents current from leaking back towards the rest of the circuit. Current consumption by the CMOS analog switch is around 100 pA; this ensures that most of the power available is applied to the memory, where it is really needed. In the stand-by mode, hundreds of A are sufficient to retain memory data.

When the 5 V supply comes back up, the resistor divider senses the presence of at least 3.5 V, and causes a new change of state in the analog switch, restoring normal operation.

Programmable Gain Amplifier

The DG419, as shown in Figure 11, allows accurate gain selection in a small package. Switching into virtual ground reduces distortion caused by $r_{DS(on)}$ variation as a function of analog signal amplitude.

GaAs FET Driver

The DG419, as shown in Figure 12 may be used as a GaAs FET driver. It translates a TTL control signal into - 8 V, 0 V level outputs to drive the gate.

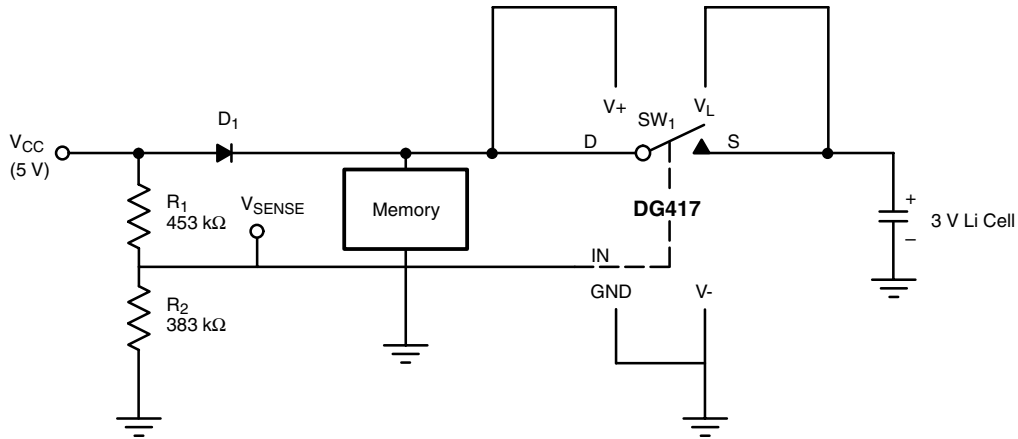


Figure 11. Micropower UPS Circuit

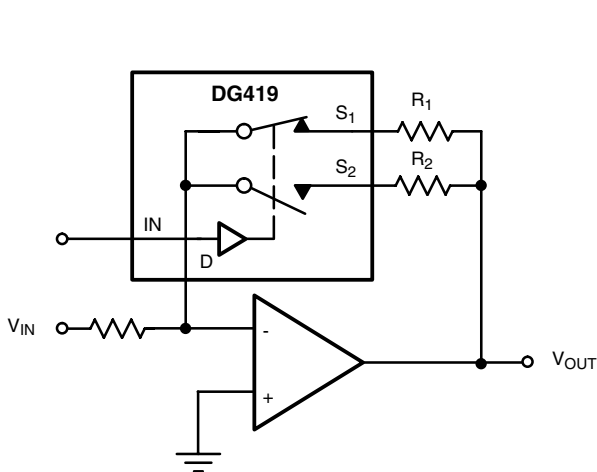


Figure 12. Programmable Gain Amplifier

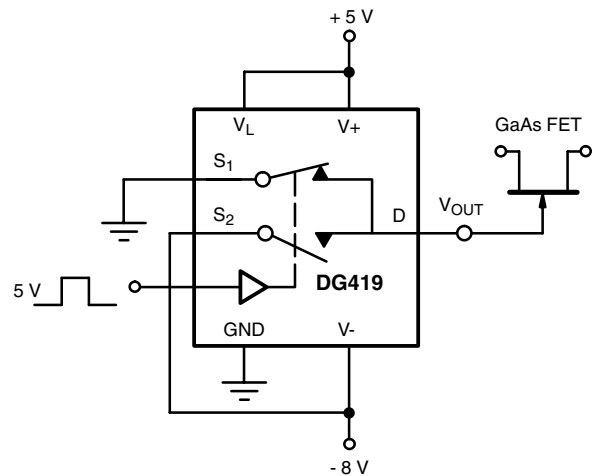


Figure 13. GaAs FET Driver

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